



제 29회 한국반도체학술대회

The 29th Korean Conference on Semiconductors

2022년 1월 24일(월)~ 26일(수) | 강원도 하이원 그랜드호텔(컨벤션타워)

2022년 1월 25일(화), 16:00-17:45

Room A (에메랄드 I, 5층)

D. Thin Film Process Technology 분과 [TA3-D] Emerging Devices

좌장: 권세훈 교수(부산대학교), 전우진 교수(경희대학교)

<p>TA3-D-1 16:00-16:15</p>	<p>Remote Doping of Octadecylphosphonic Acid Self-Assembled Monolayer Enabling High-Performance IGZO/p-Si Heterojunction Photodetectors Dong Hyun Lee and Hocheon Yoo <i>Department of Electronic Engineering, Gachon University</i></p>
<p>TA3-D-2 16:30-16:45</p>	<p>Li-Nb-O Family Deposited by Atomic Layer Deposition (ALD) for Artificial Synapse Hyun Seung Choi, Hye Rim Kim, Su Yong Park, and Tae Joo Park <i>Department of Materials Science and Chemical Engineering, Hanyang University</i></p>
<p>TA3-D-3 16:45-17:00</p>	<p>Optically Programmable Multi-State Small Molecules Memory Transistors with Channel Thickness Dependent Characteristics Seongjae Kim, Juhyung Seo, Taehyun Park, and Hocheon Yoo <i>Department of Electronic Engineering, Gachon University</i></p>
<p>TA3-D-4 17:00-17:15</p>	<p>Atomic Layer Deposited Li-Based Memristor Devices for Neuromorphic Computing Hye Rim Kim¹, Hyun Seung Choi¹, Su Youg Park¹, Gun Hwan Kim², and Tae Joo Park¹ ¹<i>Department of Materials Science and Chemical Engineering, Hanyang University,</i> ²<i>Division of Advanced Materials, KRICT</i></p>
<p>TA3-D-5 17:15-17:30</p>	<p>Photo-Induced Synaptic Behavior of Oxide Transistor with Dual Gate Dielectrics Jung Wook Lim^{1,2} and Min A Park¹ ¹<i>ETRI,</i> ²<i>Department of Advanced Device Engineering, UST</i></p>
<p>TA3-D-6 17:30-17:45</p>	<p>Solution-processed Carbon Nanotube Network Transistors with Controlled Channel Process Conditions Hanbin Lee, Ju Won Jeon, Yongwoo Lee, Dong Myong Kim, Dae Hwan Kim, Jong-Ho Bae, and Sung-Jin Choi <i>School of Electrical Engineering, Kookmin University</i></p>